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Team Nexperia



PESD1CAN

CAN bus ESD protection diode Rev. 04 — 15 February 2008

Product data sheet

Product profile

1.1 General description

PESD1CAN in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package designed to protect two automotive Controller Area Network (CAN) bus lines from the damage caused by ElectroStatic Discharge (ESD) and other transients.

1.2 Features

- Due to the integrated diode structure only one small SOT23 package is needed to protect two CAN bus lines
- Max. peak pulse power: $P_{PP} = 200 \text{ W}$ at $t_p = 8/20 \text{ μs}$
- Low clamping voltage: V_{CL} = 40 V at I_{PP} = 1 A
- Ultra low leakage current: I_{RM} < 1 nA</p>
- Typ. diode capacitance matching: $\Delta C_d/C_d = 0.1 \%$
- ESD protection up to 23 kV
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge); I_{PP} = 3 A at t_p = 8/20 μs
- Small SMD plastic package

1.3 Applications

- CAN bus protection
- Automotive applications

1.4 Quick reference data

Quick reference data

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|--------------------------|------------------------|-----|-----|-----|------|
| Per diode |) | | | | | |
| V_{RWM} | reverse standoff voltage | | - | - | 24 | V |
| C _d | diode capacitance | $f = 1 MHz; V_R = 0 V$ | - | 11 | 17 | pF |



2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|----------------|--------------------|------------------|
| 1 | cathode 1 | | |
| 2 | cathode 2 | 3 | 1 [] |
| 3 | common cathode | 1 2 | 2 3 006aaa155 |
| | | | 000aaa 155 |

3. Ordering information

Table 3. Ordering information

| Type number | Package | Package | | | | |
|-------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| PESD1CAN | - | plastic surface-mounted package; 3 leads | SOT23 | | | |

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PESD1CAN | *AN |

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|----------------------|----------------------|--------|-----|------|------|
| Per diode | | | | | | |
| P _{PP} | peak pulse power | $t_p = 8/20 \ \mu s$ | [1][2] | - | 200 | W |
| I _{PP} | peak pulse current | $t_p = 8/20 \ \mu s$ | [1][2] | - | 3 | А |
| Per device | | | | | | |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -65 | +150 | °C |
| T _{stg} | storage temperature | | | -65 | +150 | °C |

^[1] Non-repetitive current pulse $8/20~\mu s$ exponential decay waveform according to IEC 61000-4-5.

[2] Measured from pin 1 to 3 or 2 to 3.



Table 6. ESD maximum ratings

| | • | | | | | |
|------------------|---------------------------------|--------------------------------------|--------|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Max | Unit |
| Per diode | | | | | | |
| V _{ESD} | electrostatic discharge voltage | IEC 61000-4-2 (contact discharge) | [1][2] | - | 23 | kV |
| | | MIL-STD-883 (human body model) | | - | 10 | kV |

- [1] Device stressed with ten non-repetitive ESD pulses.
- [2] Measured from pin 1 to 3 or 2 to 3.

Table 7. ESD standards compliance

| Standard | Conditions |
|---|---------------------------------|
| Per diode | |
| IEC 61000-4-2; level 4 (ESD) | > 15 kV (air); > 8 kV (contact) |
| MIL-STD-883; class 3 (human body model) | > 4 kV |

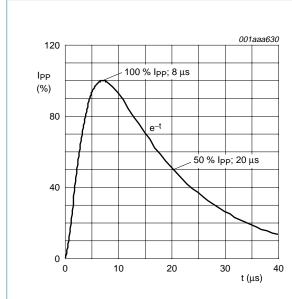


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5

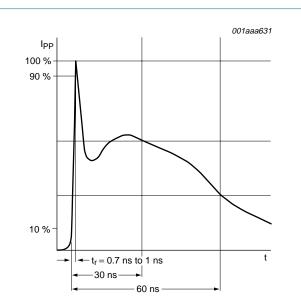


Fig 2. ESD pulse waveform according to IEC 61000-4-2

6. Characteristics

Table 8. Characteristics

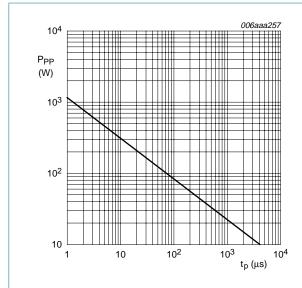
T_{amb} = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | ı | Min | Тур | Max | Unit |
|------------------|-------------------------------|--|------------|------|------|------|------|
| Per diode | | | | | | | |
| V_{RWM} | reverse standoff voltage | | - | • | - | 24 | V |
| I_{RM} | reverse leakage current | $V_{RWM} = 24 V$ | - | • | < 1 | 50 | nΑ |
| V_{BR} | breakdown voltage | $I_R = 5 \text{ mA}$ | 2 | 25.4 | 27.8 | 30.3 | V |
| C_d | diode capacitance | $f = 1 MHz; V_R = 0 V$ | - | • | 11 | 17 | pF |
| $\Delta C_d/C_d$ | diode capacitance matching | | <u>[1]</u> | | | | |
| | | $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ | - | • | 0.1 | - | % |
| | | f = 1 MHz; V _R = 2.5 V | - | • | 0.1 | - | % |
| V_{CL} | clamping voltage | | [2][3] | | | | |
| | | I _{PP} = 1 A | - | • | - | 40 | V |
| | | I _{PP} = 3 A | - | • | - | 70 | V |
| r _{dif} | differential resistance | $I_R = 1 \text{ mA}$ | - | - | - | 300 | Ω |
| | | | | | | | |

^[1] ΔC_d is the difference of the capacitance measured between pin 1 and pin 3 and the capacitance measured between pin 2 and pin 3.

^[2] Non-repetitive current pulse $8/20~\mu s$ exponential decay waveform according to IEC 61000-4-5.

^[3] Measured from pin 1 to 3 or 2 to 3.



 T_{amb} = 25 $^{\circ}C$

Fig 3. Peak pulse power as a function of exponential pulse duration; typical values

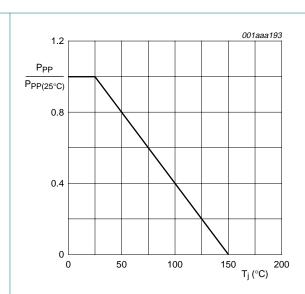
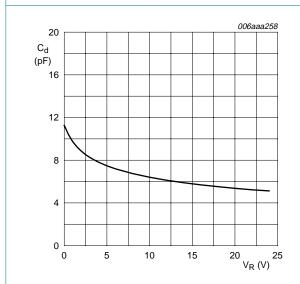


Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$

Product data sheet

Fig 5. Diode capacitance as a function of reverse voltage; typical values

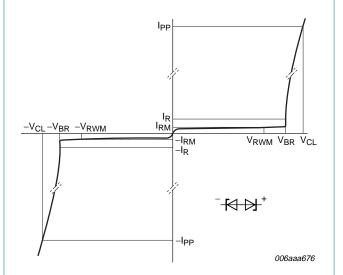


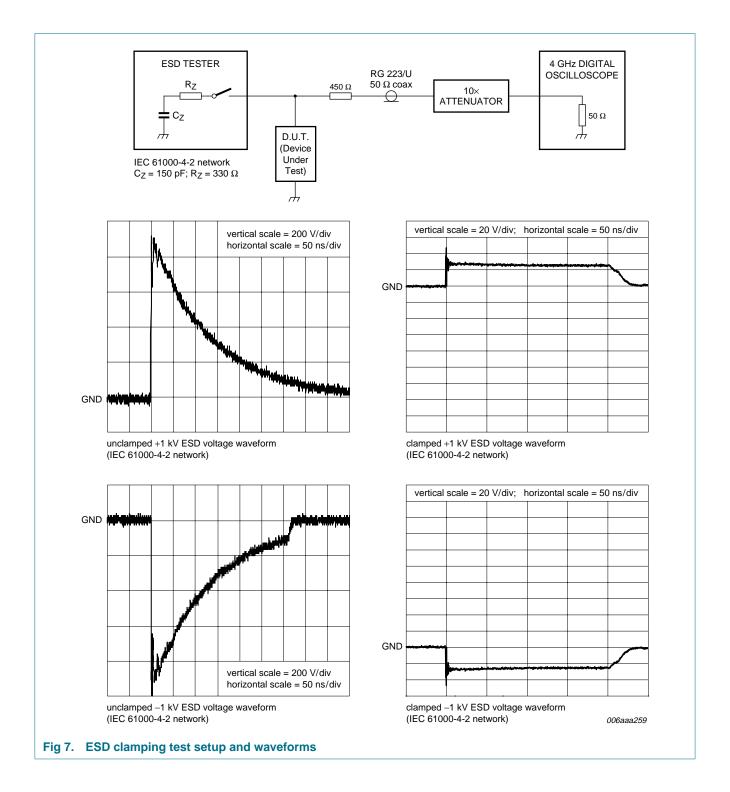
Fig 6. V-I characteristics for a bidirectional ESD protection diode

Product data sheet



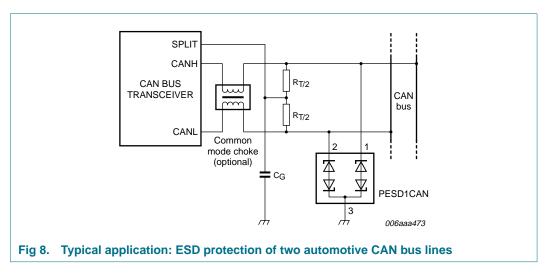
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CAN bus ESD protection diode



7. Application information

The PESD1CAN is designed for the protection of two automotive CAN bus lines from the damage caused by ESD and surge pulses. The device can be used for both, high-speed CAN bus and fault-tolerant CAN bus protection. The PESD1CAN provides a surge capability of up to 200 W per line for an $8/20~\mu s$ waveform.

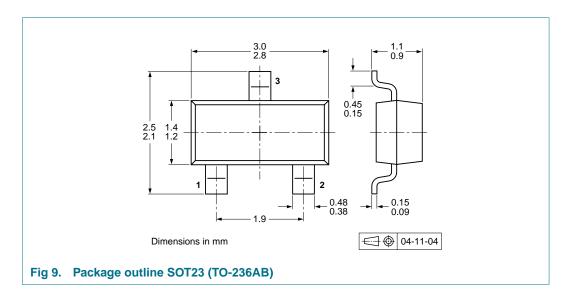


Circuit board layout and protection device placement:

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESD1CAN as close to the input terminal or connector as possible.
- 2. The path length between the PESD1CAN and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protection conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Package outline



9. Packing information

Table 9. Packing methods

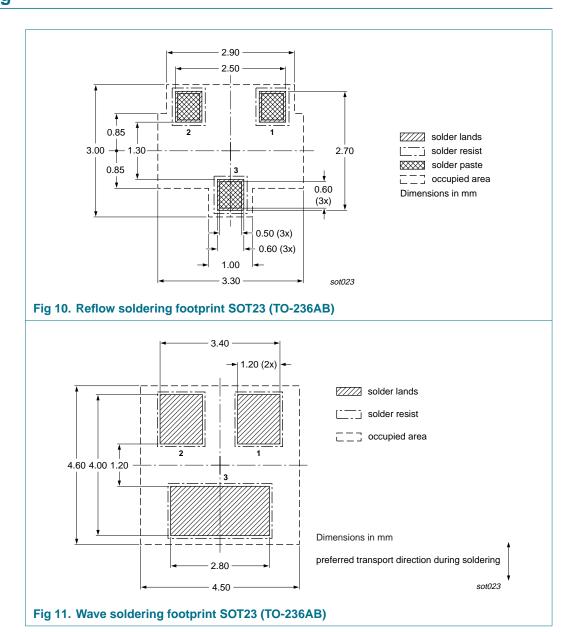
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing qu | uantity |
|-------------|---------|--------------------------------|------------|---------|
| | | | 3000 | 10000 |
| PESD1CAN | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |

[1] For further information and the availability of packing methods, see Section 13.



10. Soldering





11. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|--|---------------|------------|
| PESD1CAN_4 | 20080215 | Product data sheet | - | PESD1CAN_3 |
| Modifications: | | Features": list item for diode caracteristics": $\Delta C_d/C_d$ diode cap | | |
| PESD1CAN_3 | 20070521 | Product data sheet | - | PESD1CAN_2 |
| PESD1CAN_2 | 20051017 | Product data sheet | - | PESD1CAN_1 |
| PESD1CAN_1 | 20050125 | Objective data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PESD1CAN

CAN bus ESD protection diode

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